

# Infrared Chameleon:

*Graphene, Surrounding Materials, and the Primacy of Their Interaction on Photodetection*

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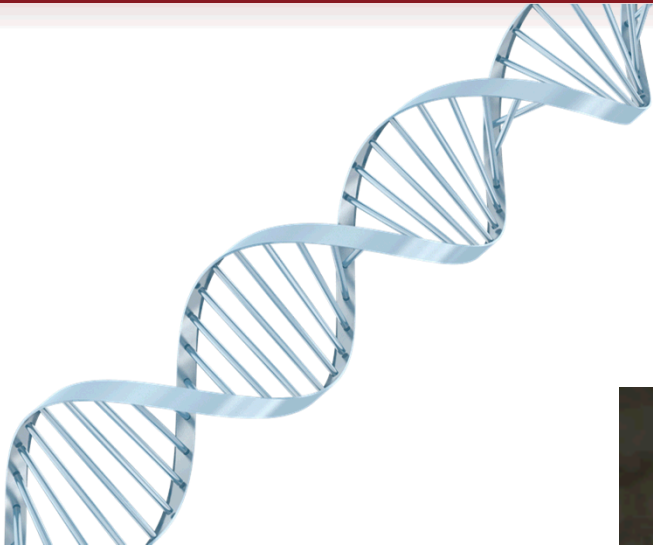
Allister Hamilton

R. Shaffer, I. Ruiz



# What makes me, me?

## Genetic, Intrinsic



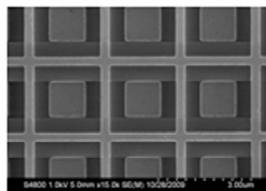
## Environment



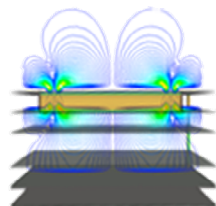
**Takeaway:** We are who we are **AND** what we're around.



## Nanoantenna Field Enhancement

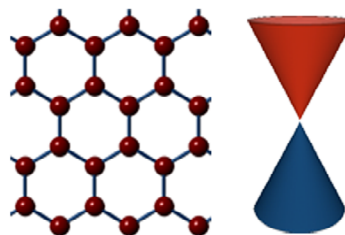


Increased Absorption



+

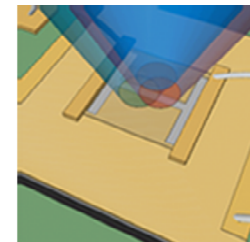
## Graphene



Tunable Response

=

## Tunable Detector



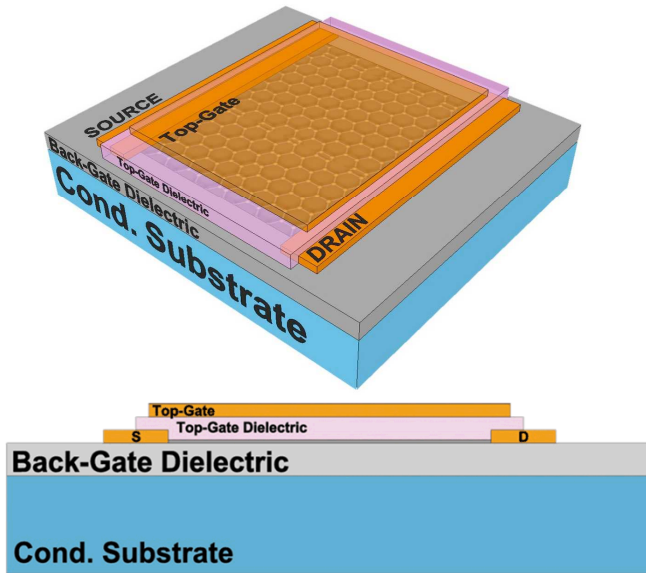
Hyperspectral Pixel

## Challenge

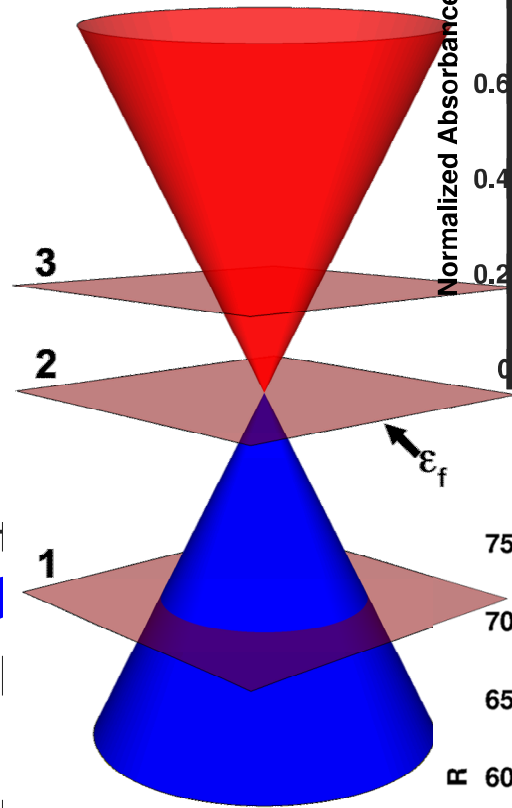
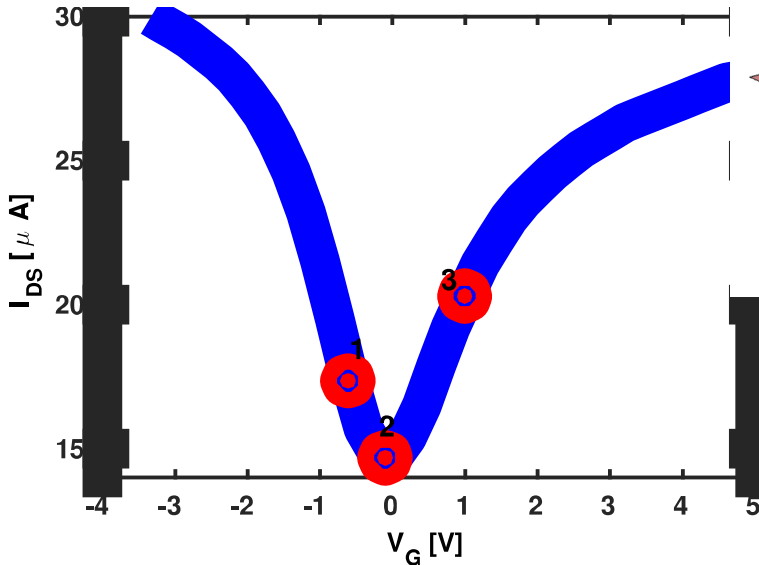
1. Can graphene absorb enough light?
2. Can its absorption be tuned?
3. Can the photogenerated charge be collected?

# DNA: Graphene Tunability

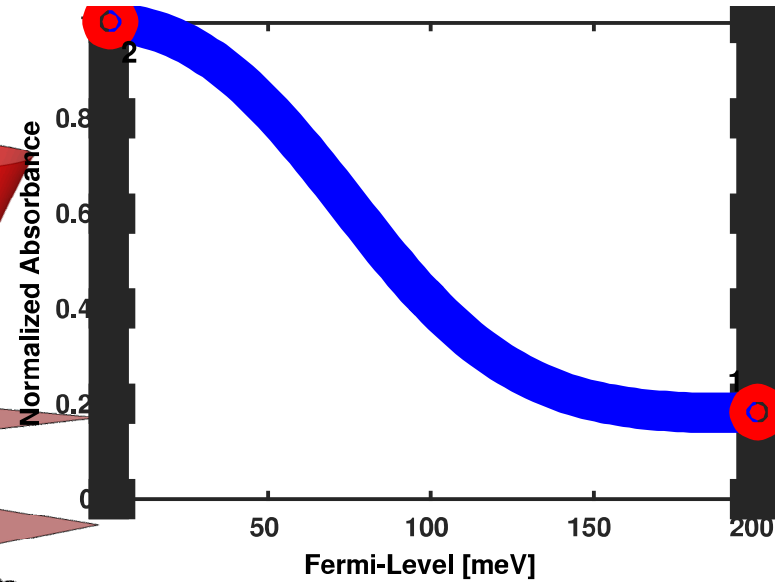
## Graphene Transistor



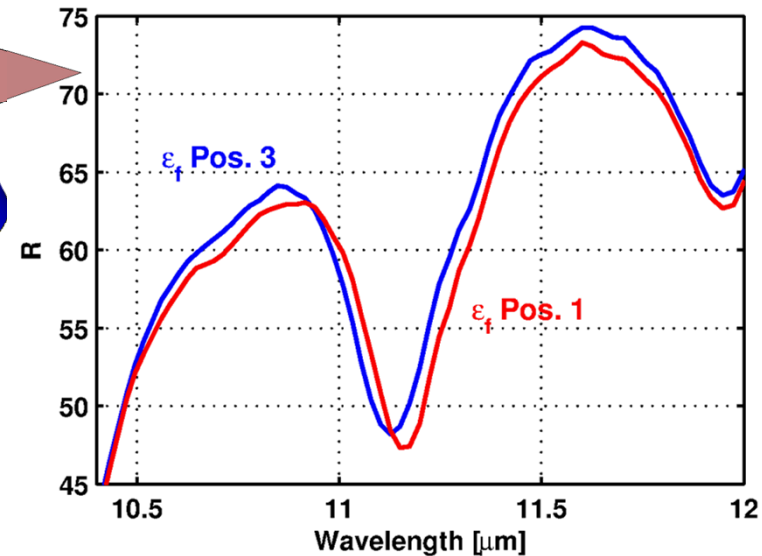
## Tunable Resistance



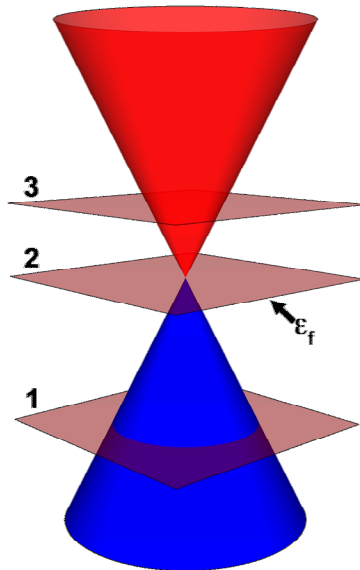
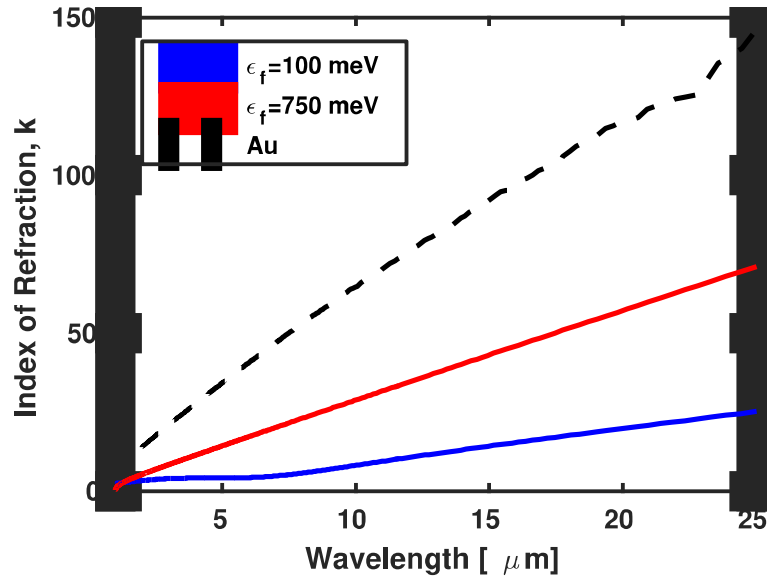
## Tunable Absorber



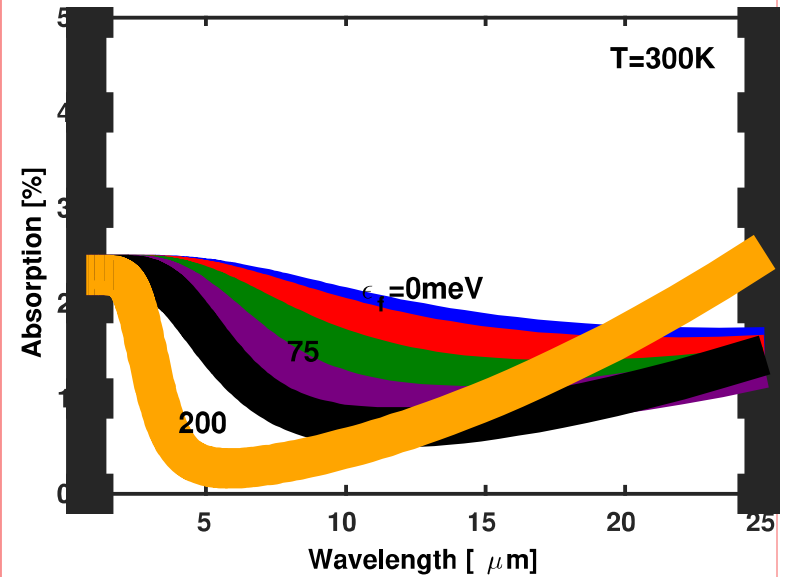
## Tunable Nanoantenna



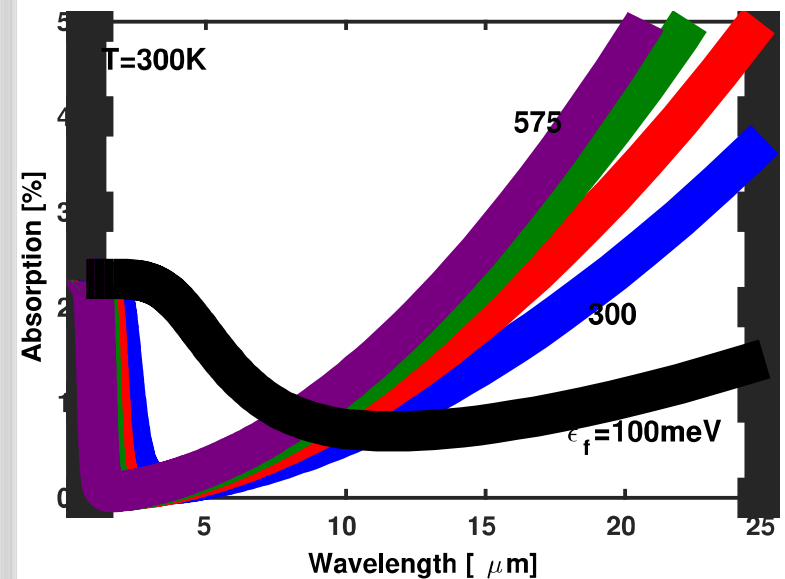
# Myth: Graphene Absorbs 2.3%



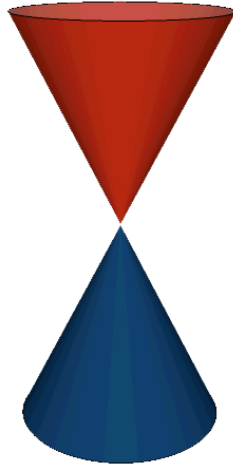
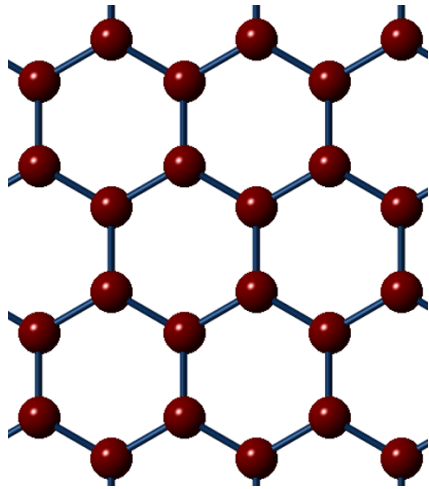
Interband



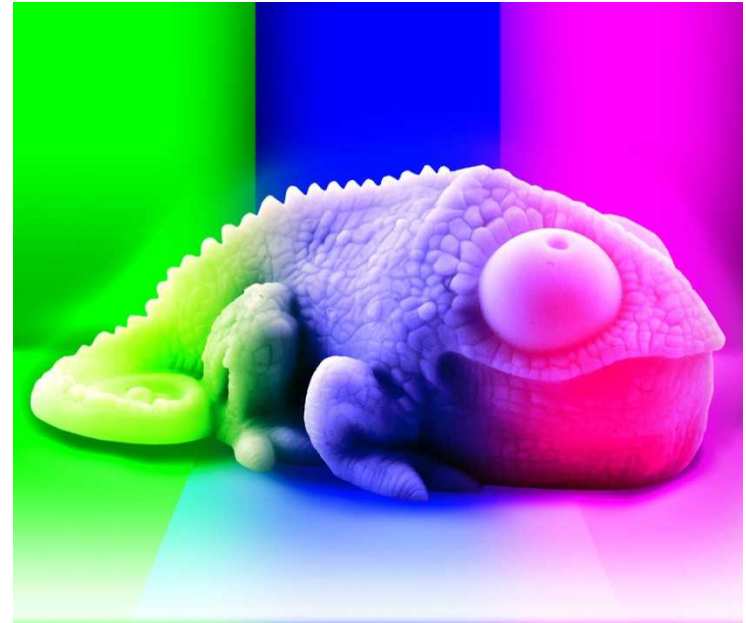
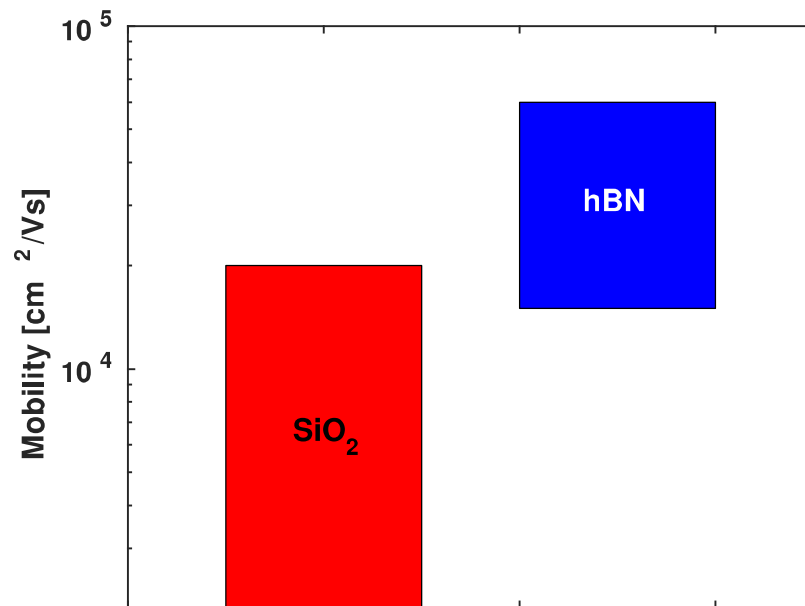
Intraband



# Env.: Graphene & Peer Pressure



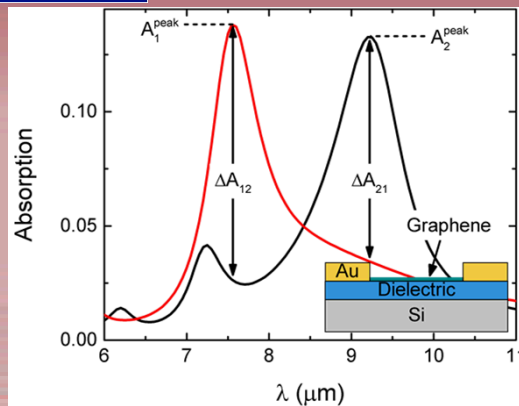
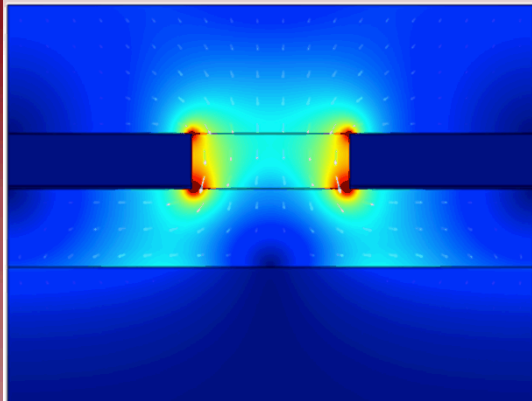
**D.A.R.E.**<sup>®</sup>



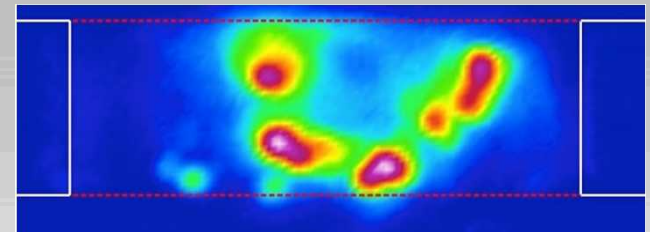
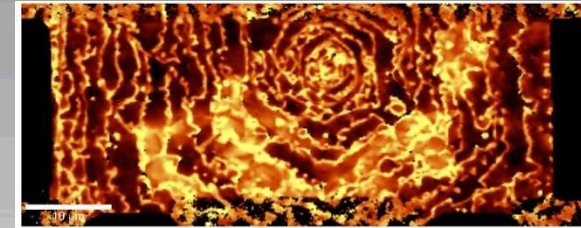
# Premise & Path

**PREMISE:** Graphene enabled hyperspectral detection dictated by material itself (DNA) & those adjacent (environment).

## Light Absorption



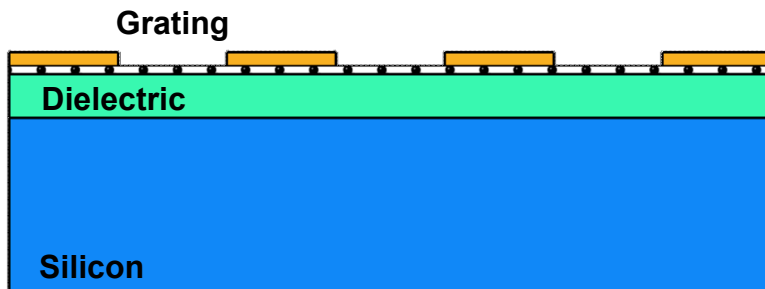
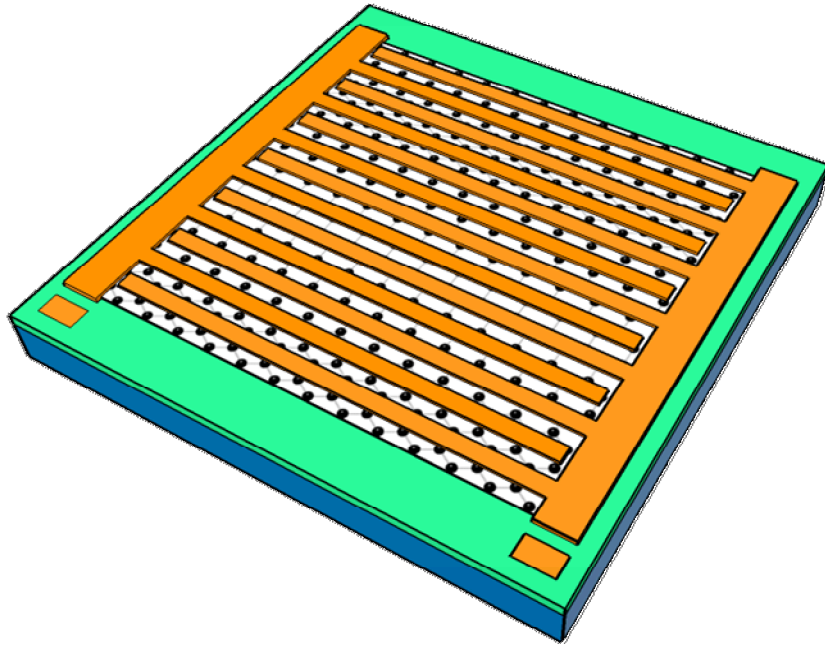
## Charge Collection



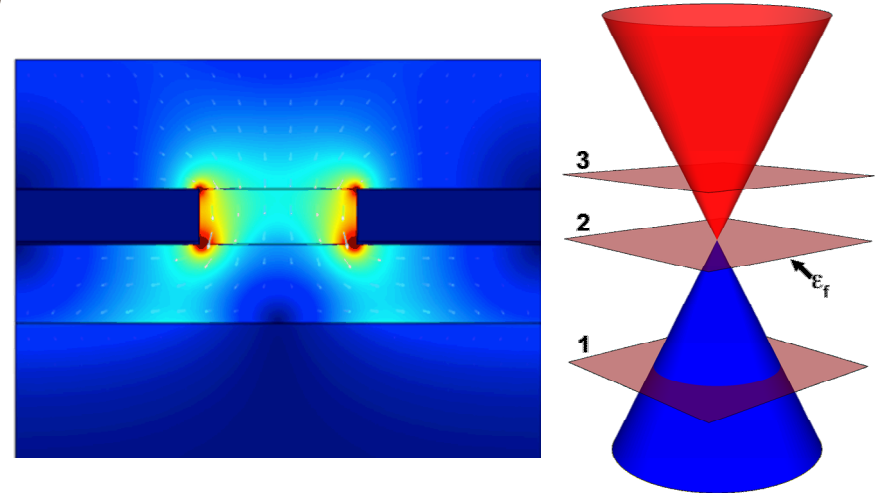


# Method & Approach

## Architecture & Material Silos

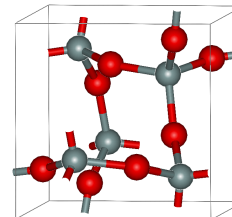


## Electromagnetic Modeling

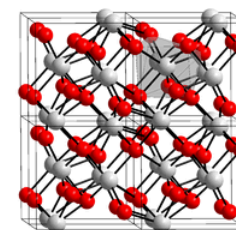


## Assess Dielectric Influence

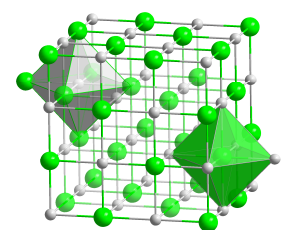
$\text{SiO}_2$



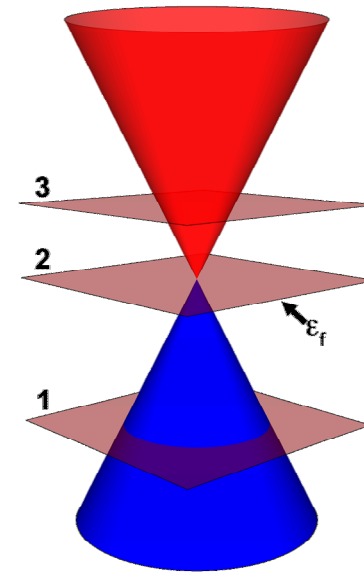
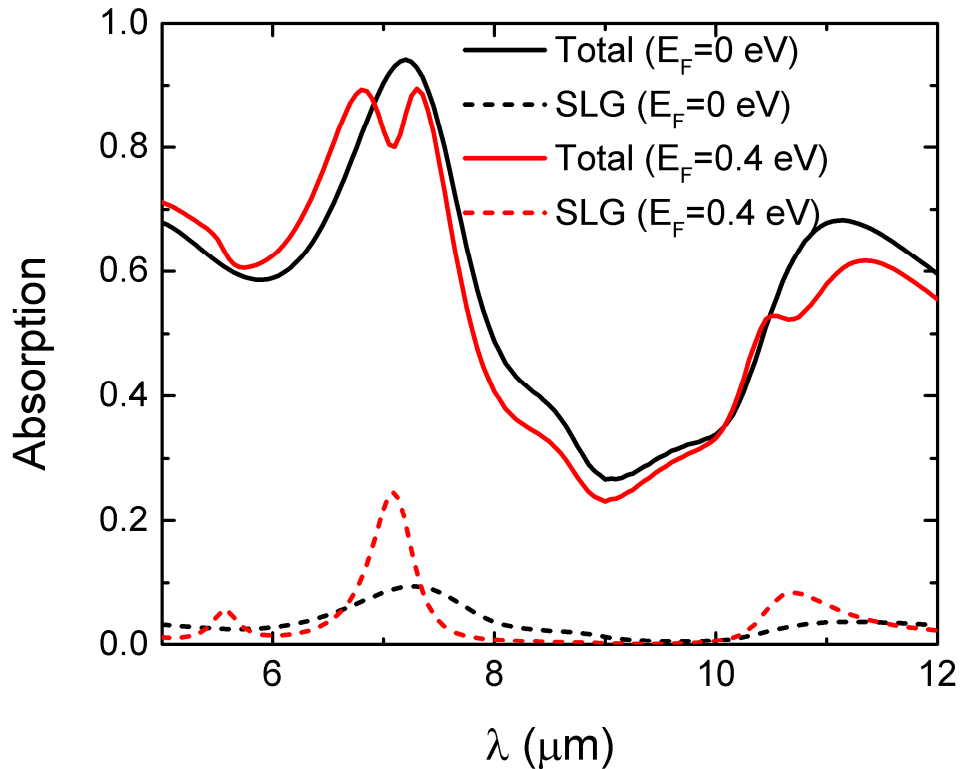
$\text{HfO}_2$



$\text{MgO}$



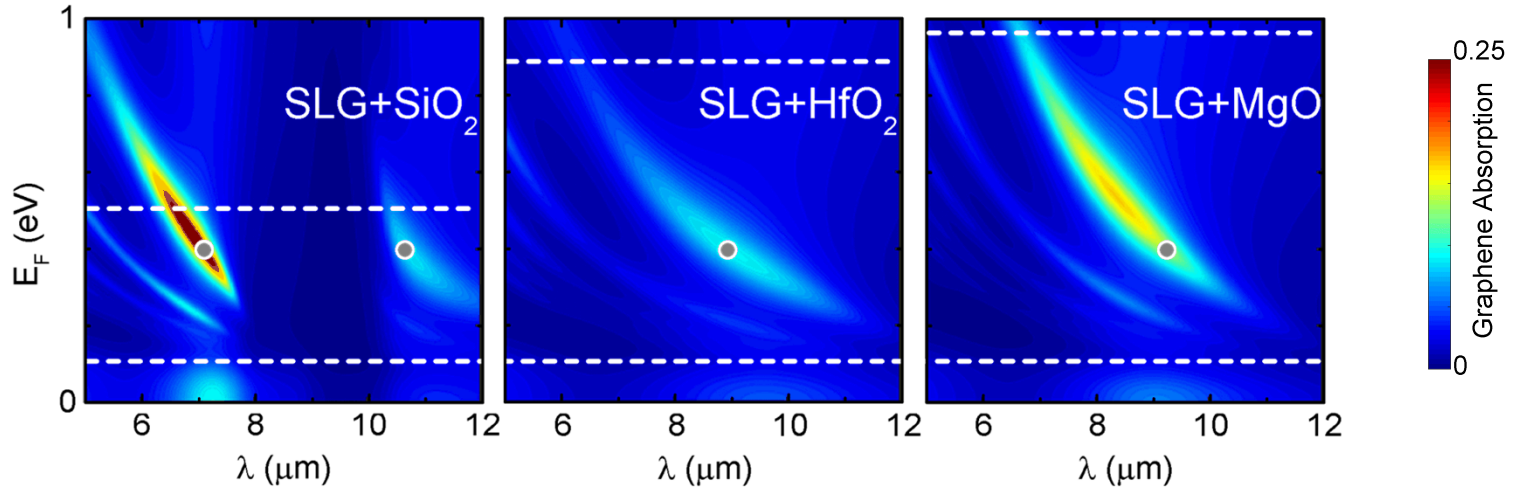
# Does the Antenna Work?



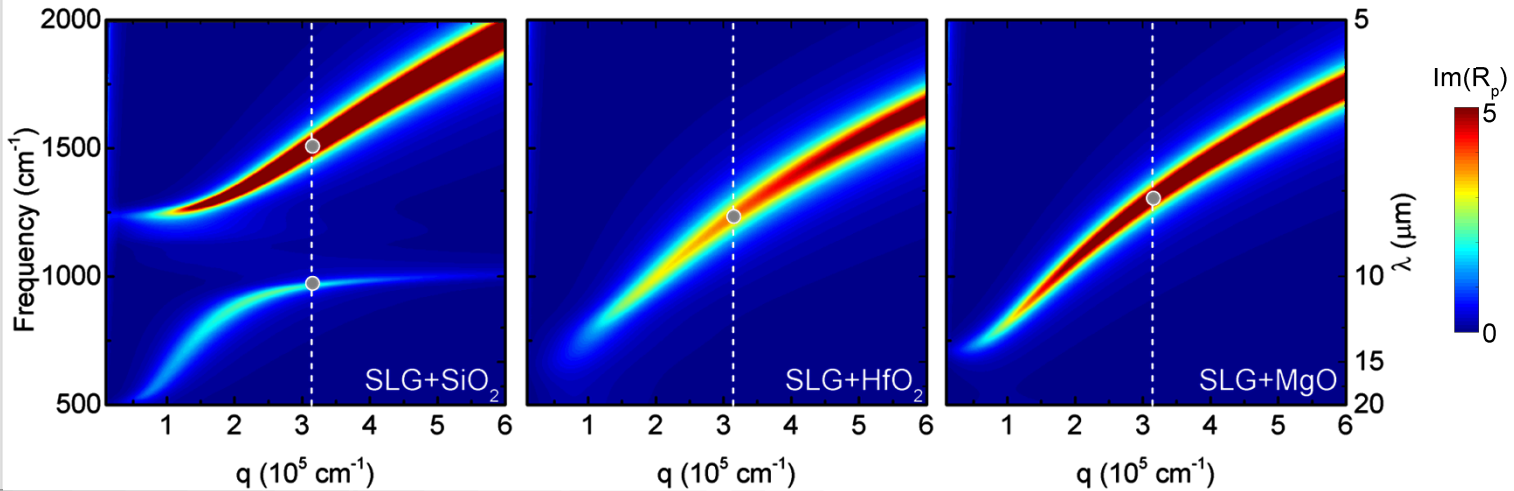
1. 10x increase in absorption over “as is” graphene BUT
  2. Most absorption occurs in substrate
- Must design nanoantenna for absorption IN graphene**

# “Surrounding” Absorption

Absorption

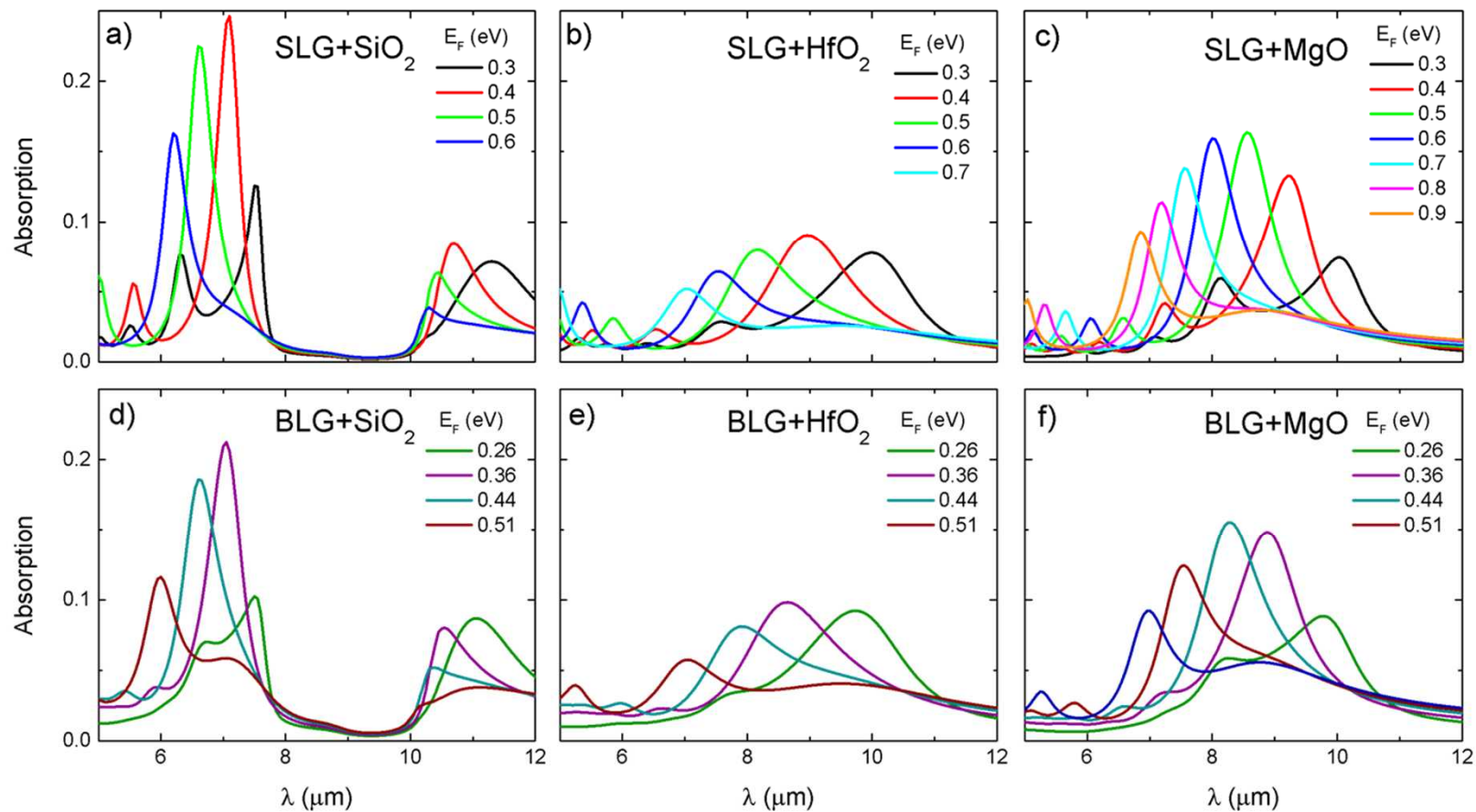


Plasmon



**Takeaway:** Plasmons drive absorption. Dielectric defines plasmon.

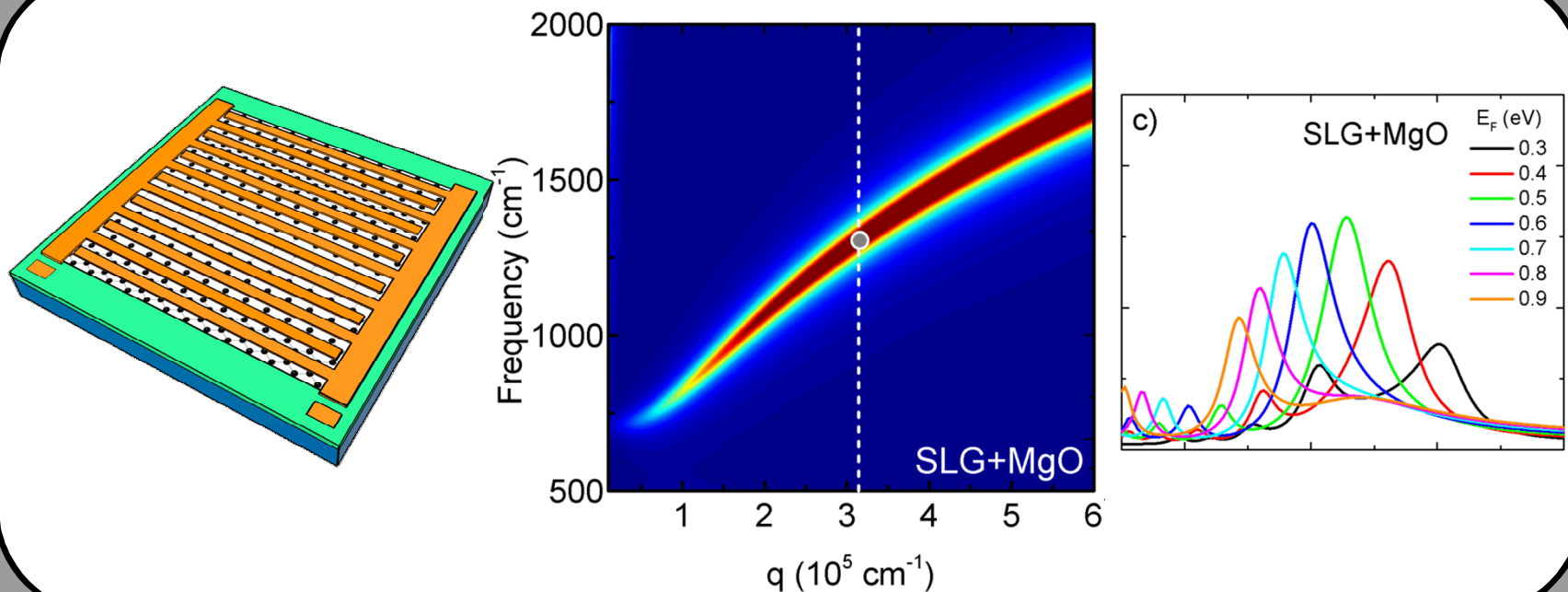
# Tunability via Plasmon Excitement



1. Tunable absorption >10% over micron ranges
2. Dielectric defines spectral response

**Bilayer graphene provides little to no advantage**

# Take Home Points

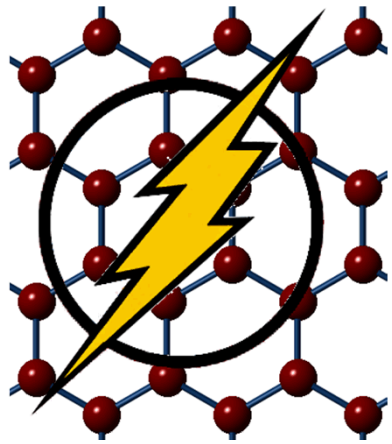


1. Plasmon excitement creates large graphene absorption.
  2. Plasmon dispersion defined by surrounding medium.
- Absorption can be tuned over microns.**



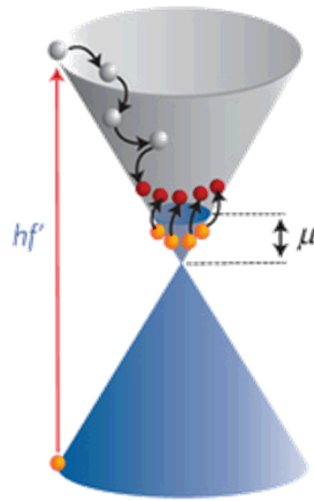
# Can we collect the generated charge?

## Good News



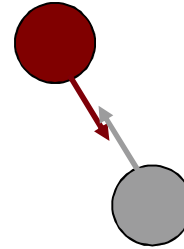
High Mobility

Hot Carrier  
Generation



## Bad News

Fast  
Recombination



Environment

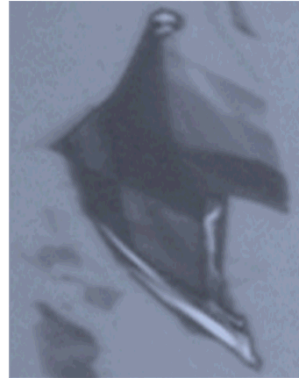


## GUIDING QUESTION

What determines charge transport in “real life”?

# “Brands” of Graphene

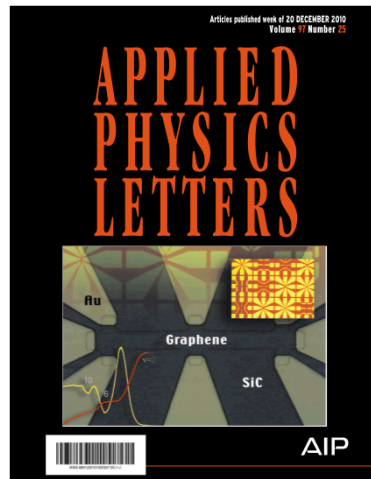
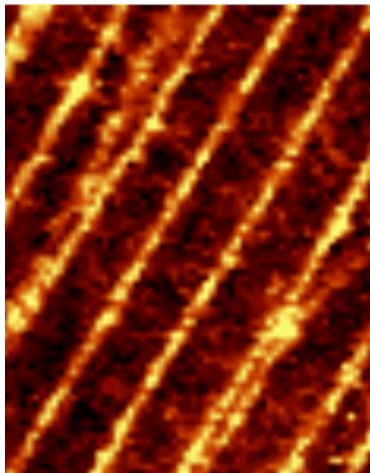
## Exfoliated



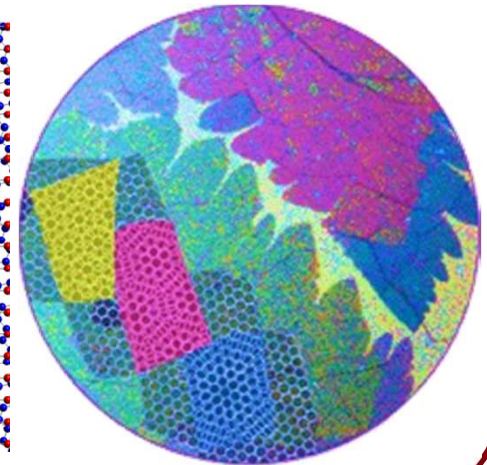
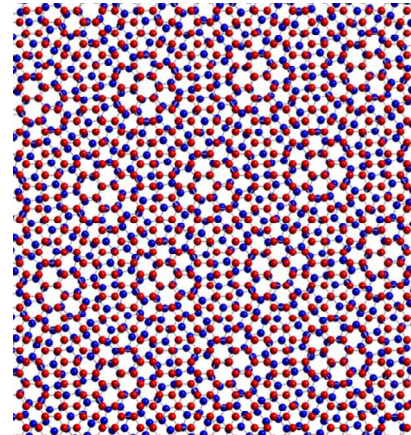
## Copper Based CVD



## Epitaxial on SiC

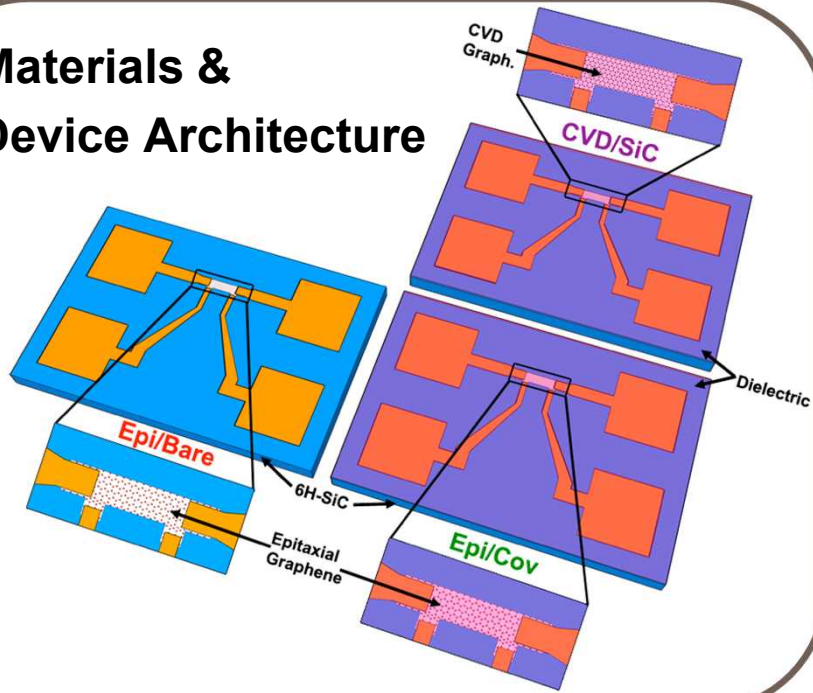


## Twisted Bilayer Graphene

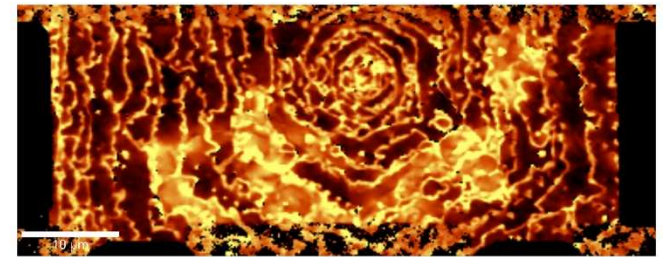
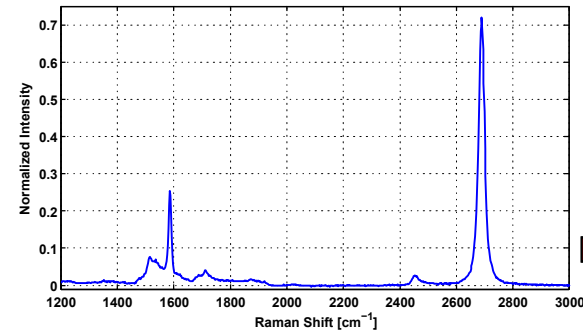


# Method & Approach

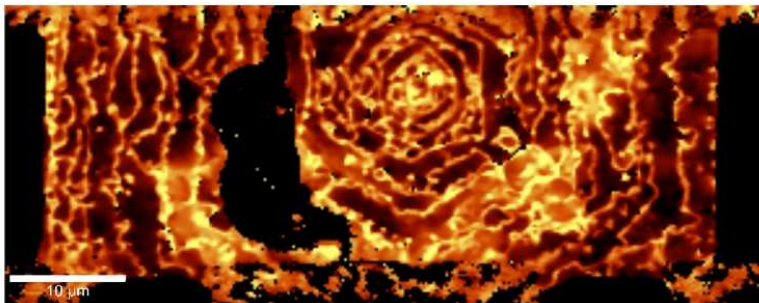
## Materials & Device Architecture



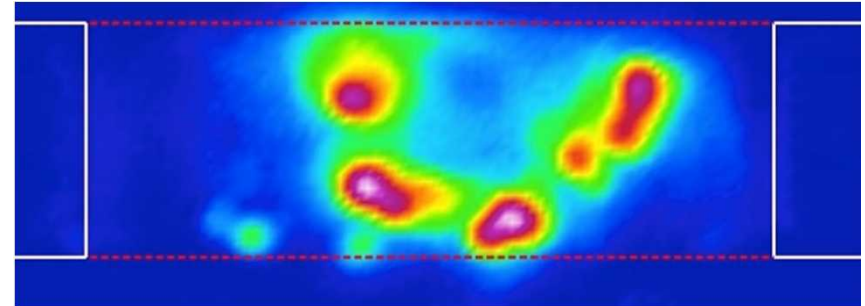
## 1. Pre-Raman Imaging



## 3. Post-Raman Imaging

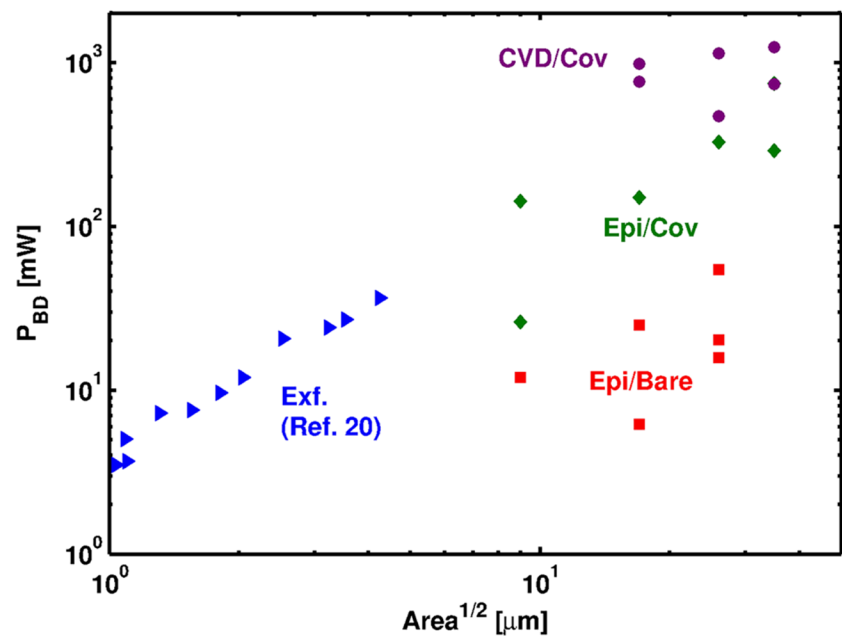


## 2. Infrared Thermography



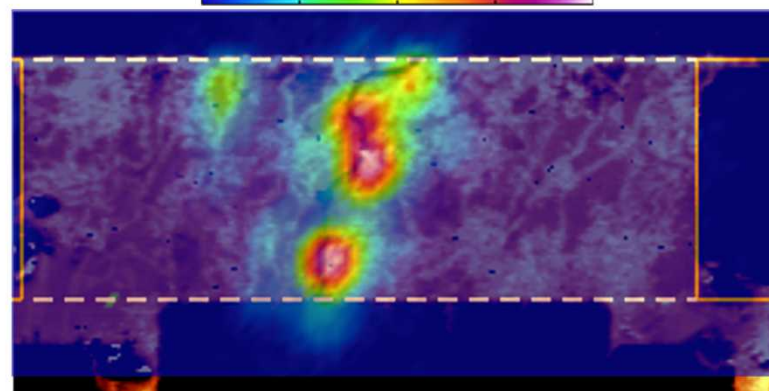
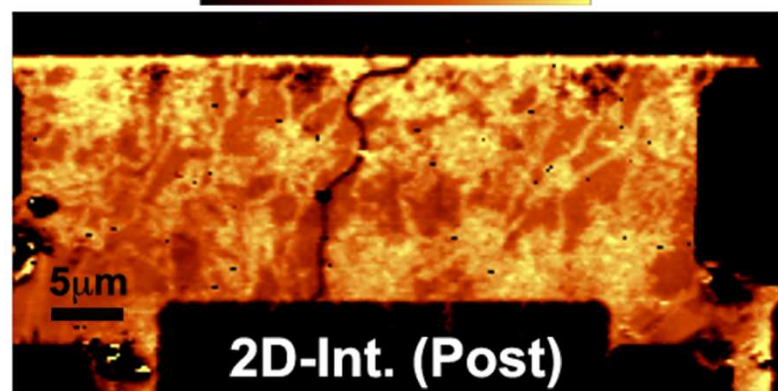
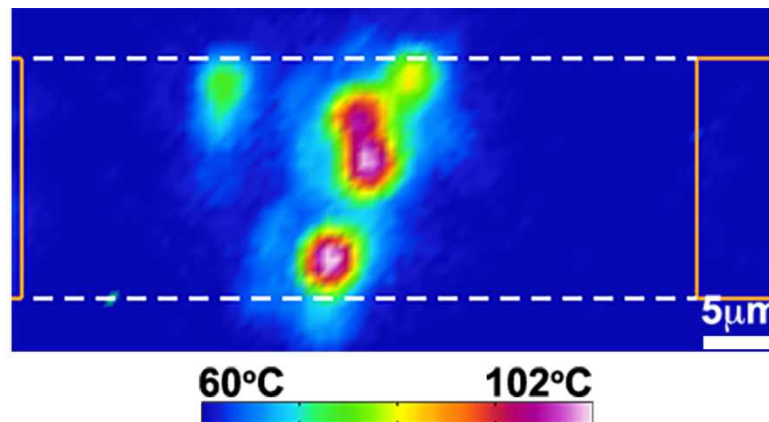
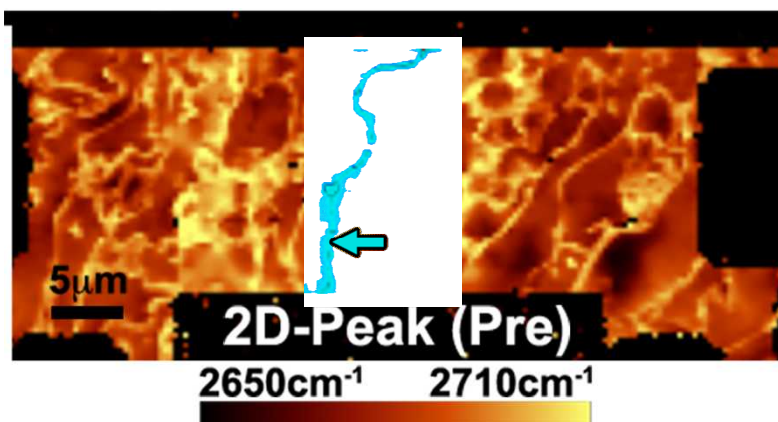
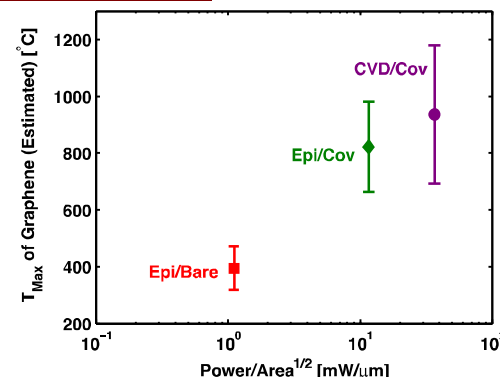
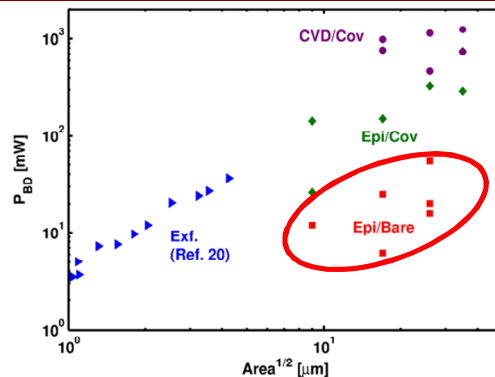
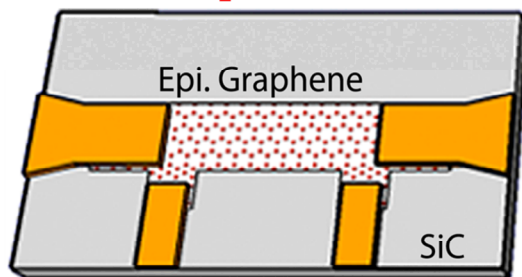


# Graphene Dependent Failure



# Epi/Bare: Low Power Failure

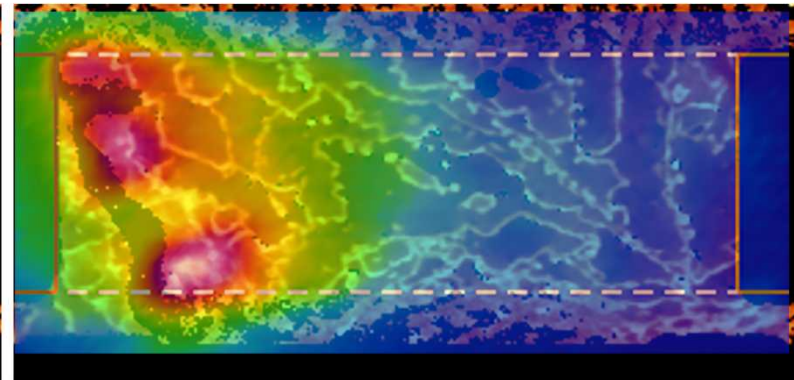
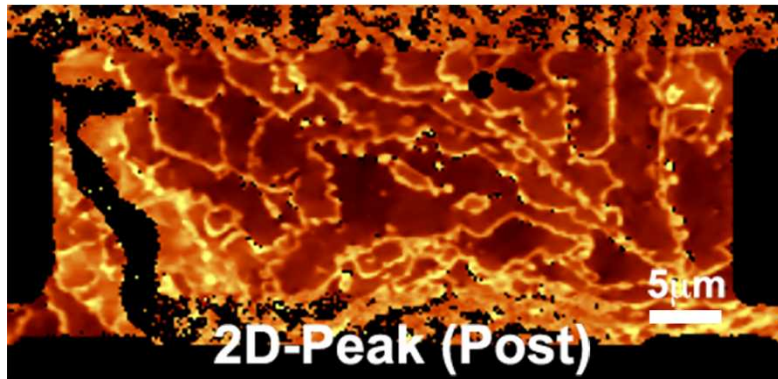
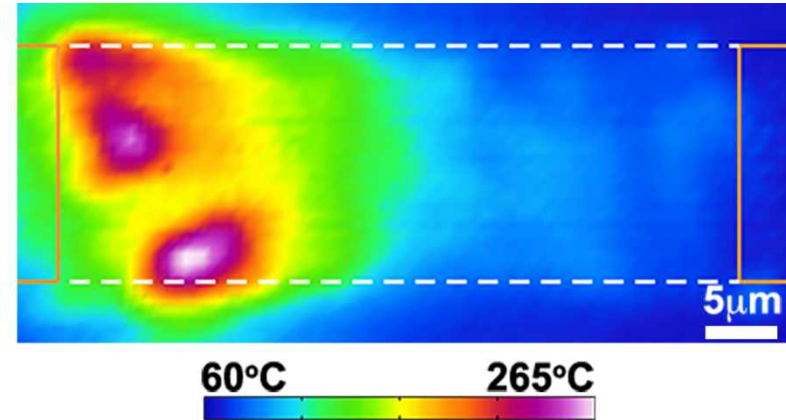
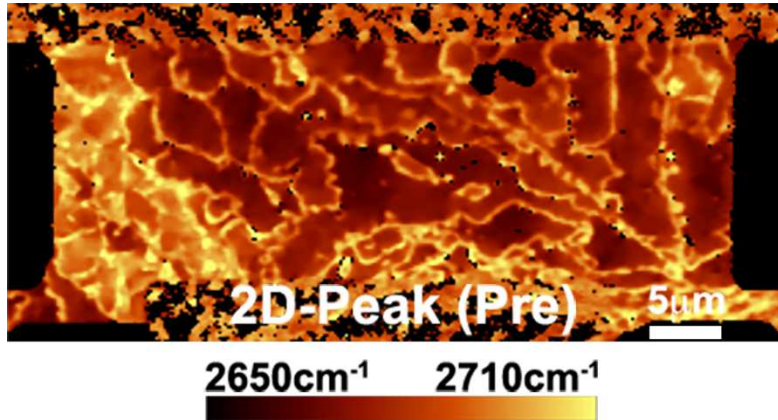
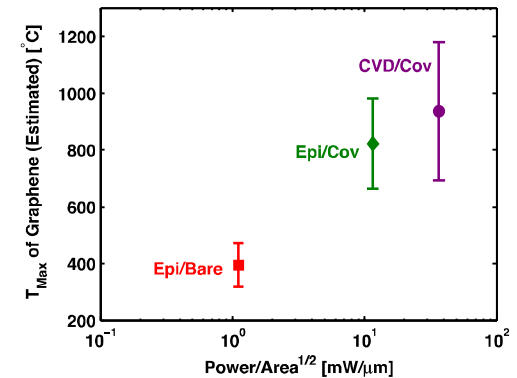
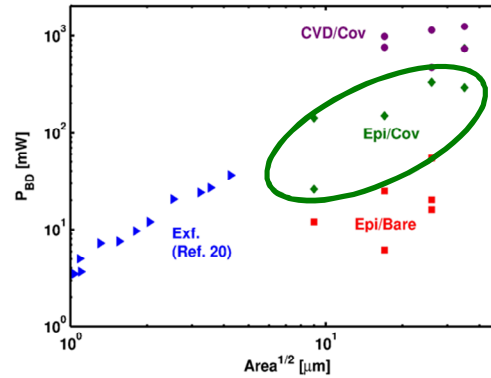
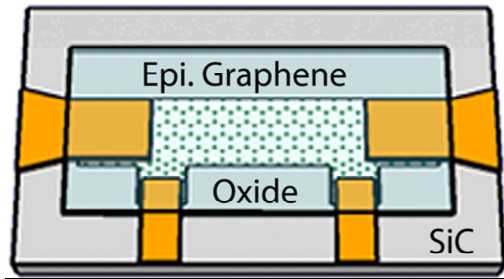
## Epi/Bare





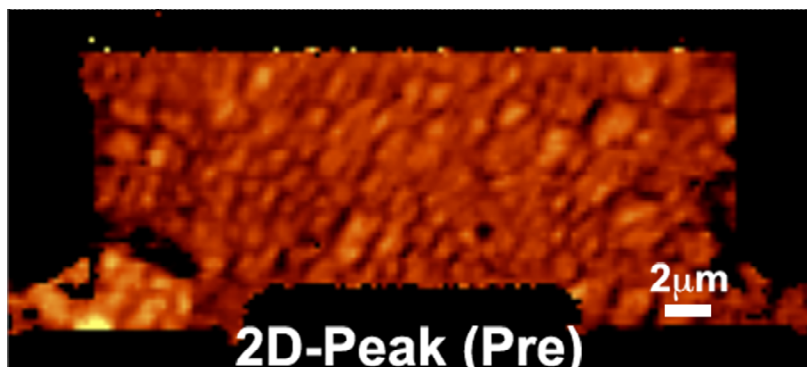
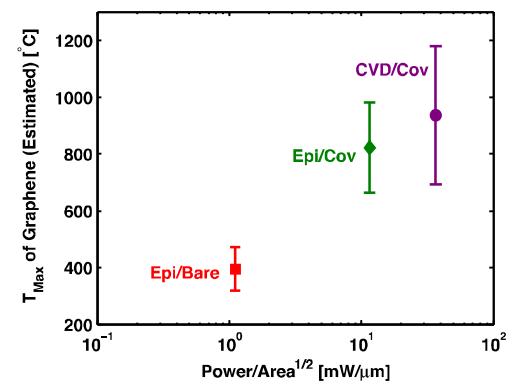
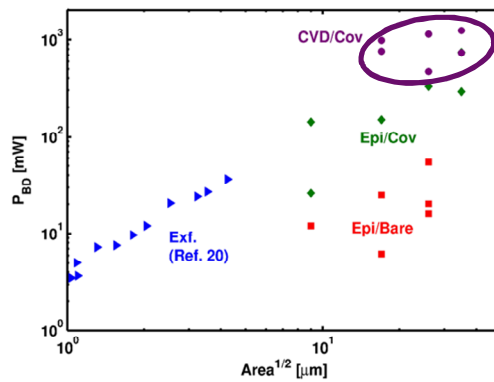
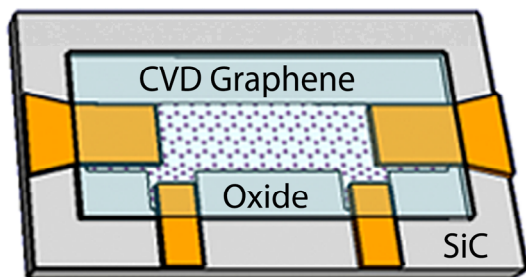
# Epi/Cov: Middling Power Failure

## Epi/Cov

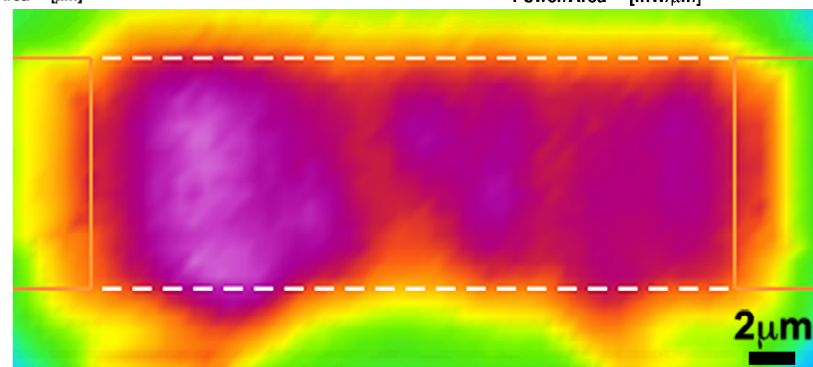


# CVD/Cov: High Power Failure

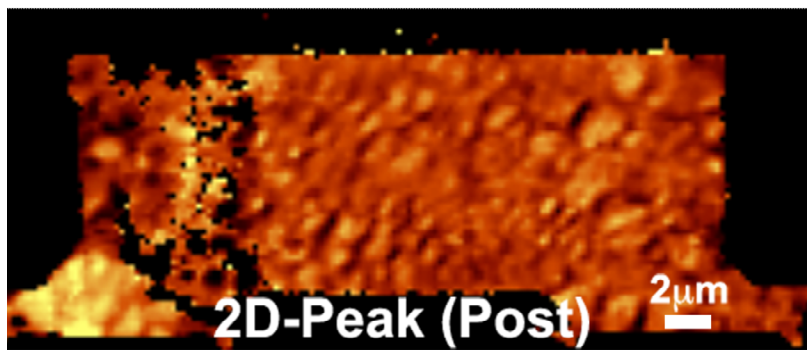
## CVD/Cov



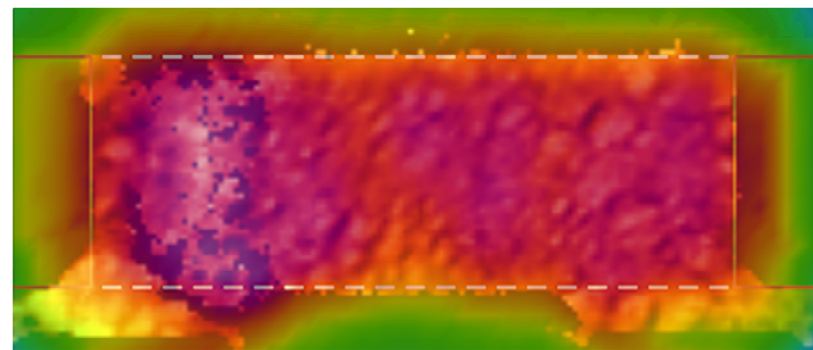
2675 $cm^{-1}$  2695 $cm^{-1}$



60 $^{\circ}C$  300 $^{\circ}C$



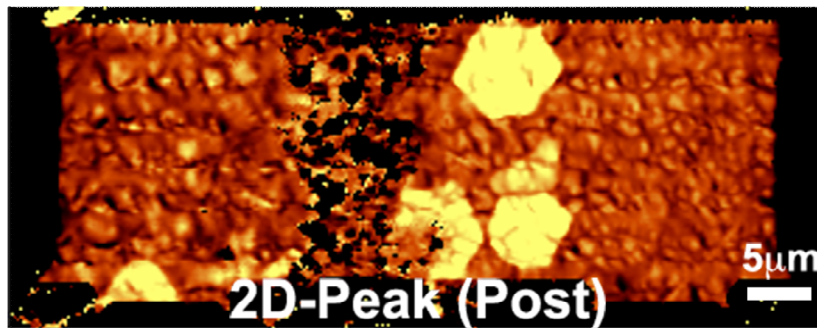
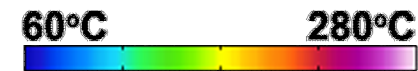
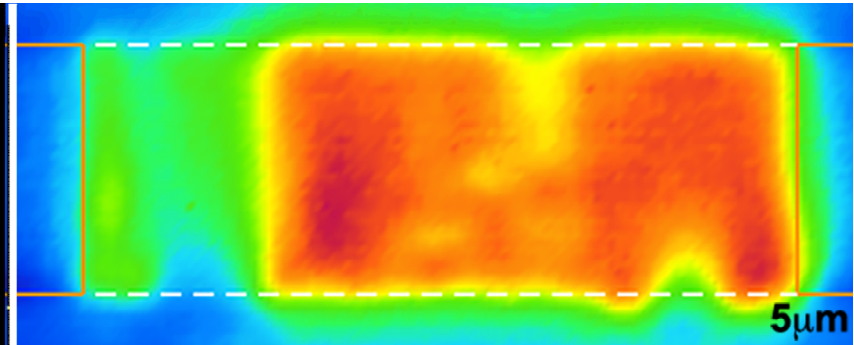
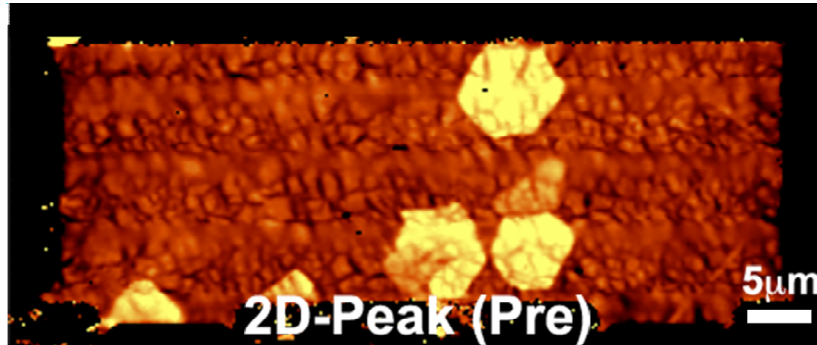
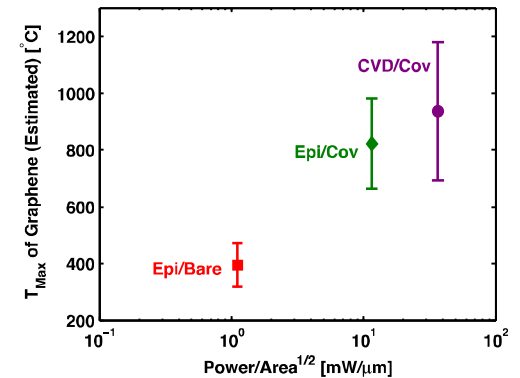
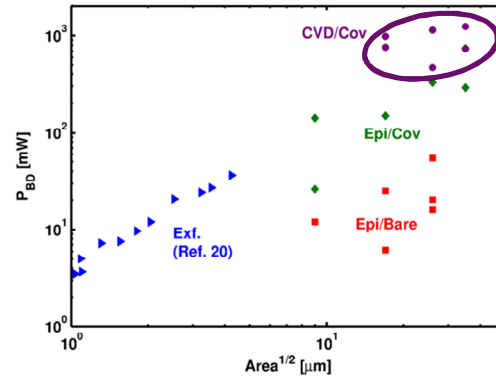
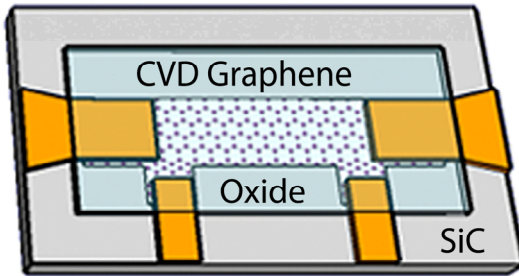
2D-Peak (Post)



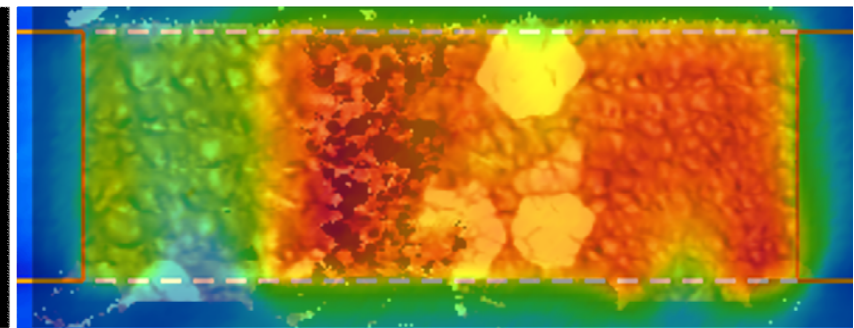


# CVD/Cov: High Power Failure

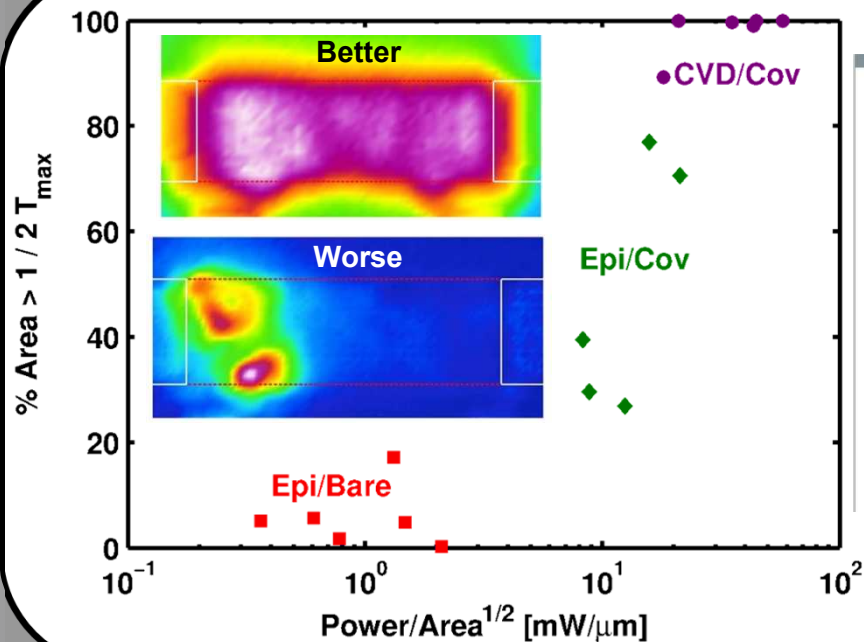
## CVD/Cov



2D-Peak (Post)



# Take Home Message



## SCIENTIFIC REPORTS

OPEN

### Self-Heating and Failure in Scalable Graphene Devices

Thomas E. Beechem, Ryan A. Shaffer, John Nogan, Taisuke Ohta, Allister B. Hamilton, Anthony E. McDonald & Stephen W. Howell

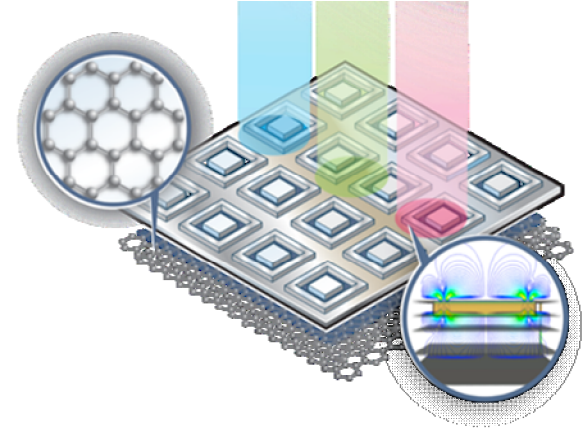
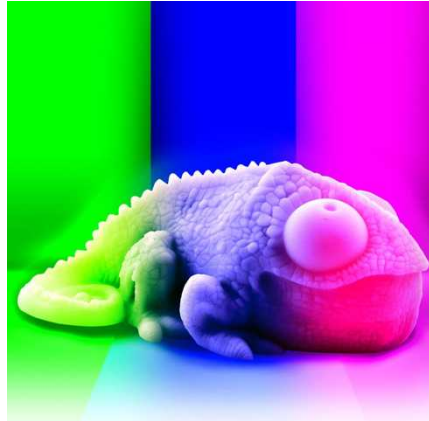
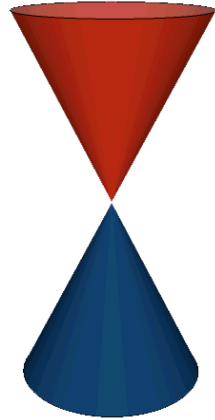
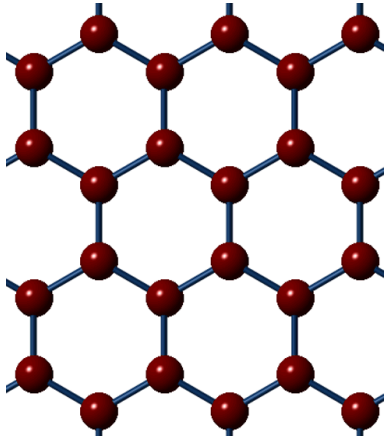
Received: 30 January 2016

Accepted: 27 April 2016

Published: 09 June 2016

Self-heating induced failure of graphene devices synthesized from both chemical vapor deposition (CVD) and epitaxial means is compared using a combination of infrared thermography and Raman imaging. Despite a larger thermal resistance, CVD devices dissipate >3x the amount of power before failure than their epitaxial counterparts. The discrepancy arises due to morphological irregularities implicit to the graphene synthesis method that induce localized heating. Morphology, rather than thermal resistance, therefore dictates power handling limits in graphene devices.

1. Power handling determined by ability to uniformly Joule-heat.
  2. Joule-heating distribution determined by morphology of graphene.
- Interlayer Interactions determine morphology.**



**Takeaway:** Hyperspectral graphene based detection promising. Surroundings as important to photodetection as graphene itself.